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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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H5N5006LD, H5N5006LS, H5N5006LM

Silicon N Channel MOS FET High Speed Power Switching

REJ03G1115-0100

(Previous: ADE-208-1549)

Rev.1.00 Apr 07, 2006

Features

- Low on-resistance
- Low leakage current
- High speed switching
- Low gate charge
- Avalanche ratings

Outline

RENESAS Package code: PRSS0004AE-A RENESAS Package code: PRSS0004AE-B (Package name: LDPAK (L))



H5N5006LD

RENESAS Package code: PRSS0004AE-C (Package name: LDPAK (S)-(2))



H5N5006LM

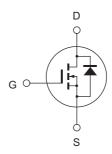
(Package name: LDPAK (S)-(1))



1. Gate

- 2. Drain
- 3. Source
- 4. Drain





Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	500	V
Gate to source voltage	V _{GSS}	±30	V
Drain current	I _D	3.5	Α
Drain peak current	I _{D (pulse)} Note 1	14	Α
Body to drain diode reverse drain current	I _{DR}	3.5	Α
Avalanche current	I _{AP} Note 3	3.5	Α
Channel dissipation	Pch Note 2	50	W
Channel to case Thermal Impedance	θ ch-c	2.5	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at $Tc = 25^{\circ}C$

3. Tch ≤ 150°C

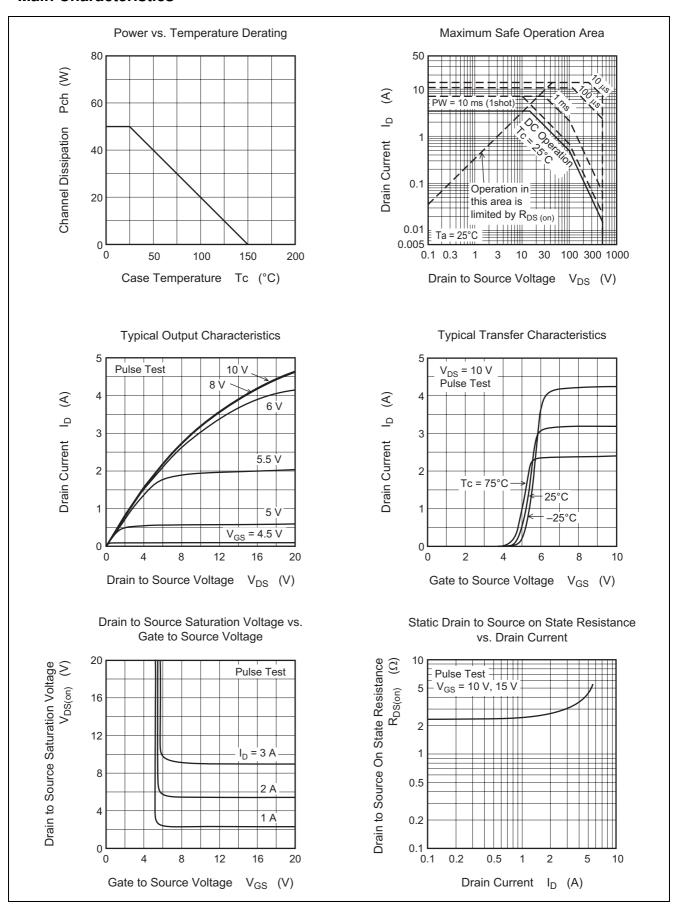
Electrical Characteristics

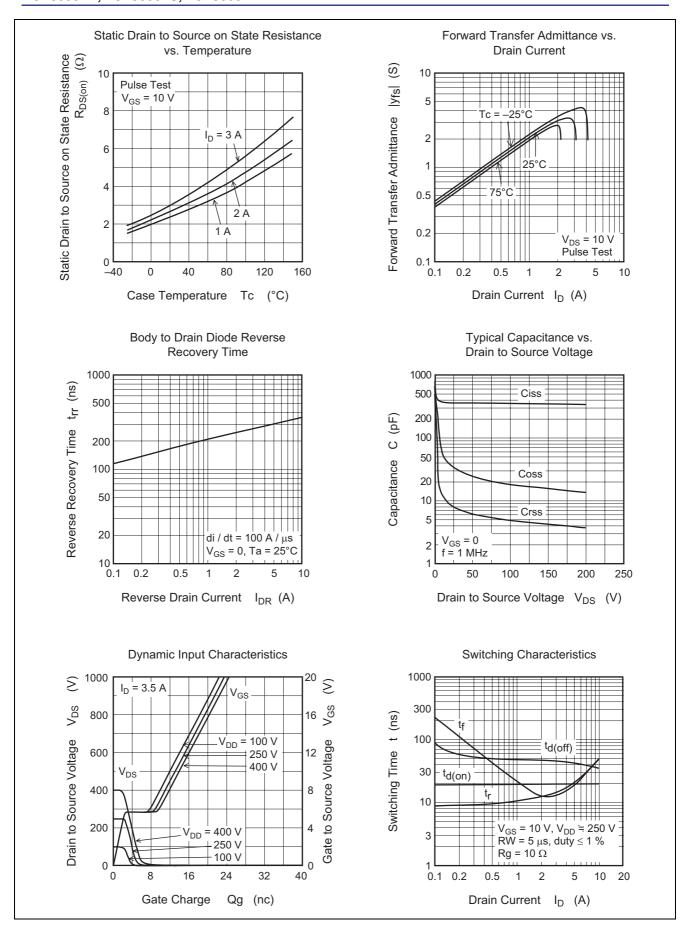
 $(Ta = 25^{\circ}C)$

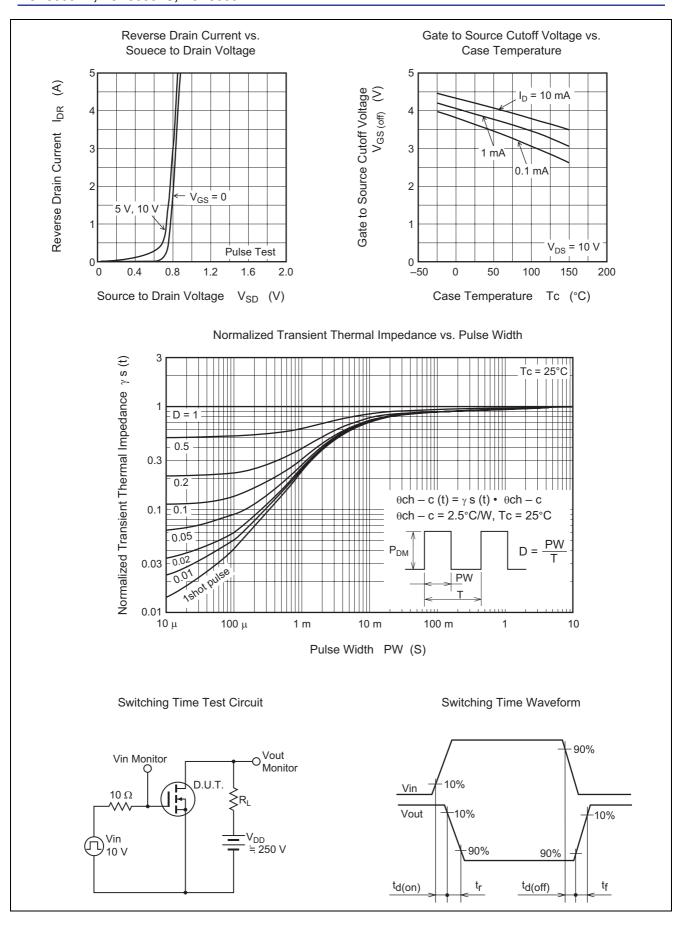
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR) DSS}	500	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 500 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS (off)}	3.0	_	4.5	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	R _{DS (on)}	_	2.5	3.0	Ω	$I_D = 1.75 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 4}}$
Forward transfer admittance	y _{fs}	1.8	3.0	_	S	$I_D = 1.75 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note 4}}$
Input capacitance	Ciss	_	365	_	рF	V _{DS} = 25 V
Output capacitance	Coss	_	35	_	рF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	8	_	рF	f = 1 MHz
Turn-on delay time	t _{d (on)}	_	20	_	ns	$V_{DD}\cong 250~V,~I_D=1.75~A$
Rise time	t _r	_	13	_	ns	$R_L = 143 \Omega$
Turn-off delay time	t _{d (off)}	_	48	_	ns	$V_{GS} = 10 \text{ V}$
Fall time	t _f	_	14	_	ns	$Rg = 10 \Omega$
Total gate charge	Qg	_	14	_	nC	V _{DD} = 400 V
Gate to source charge	Qgs	_	2	_	nC	$V_{GS} = 10 \text{ V}$
Gate to drain charge	Qgd	_	8	_	nC	$I_D = 3.5 A$
Body to drain diode forward voltage	V_{DF}	_	0.85	1.3	V	$I_F = 3.5 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time	t _{rr}	_	280	_	ns	$I_F = 3.5 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery charge	Qrr	_	0.8	_	μC	di _F /dt = 100 A/μs

Note: 4. Pulse test

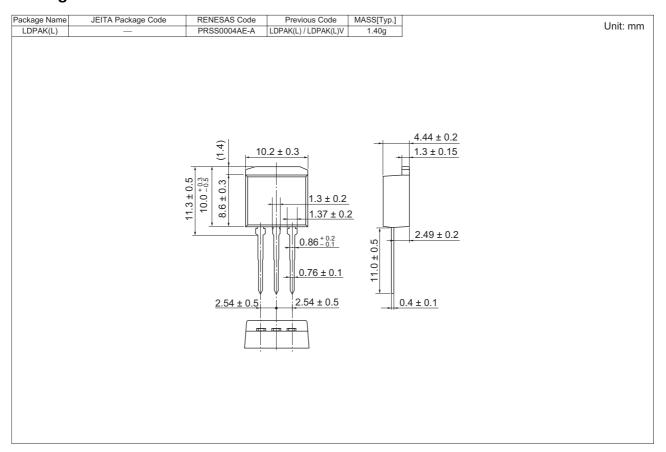
Main Characteristics

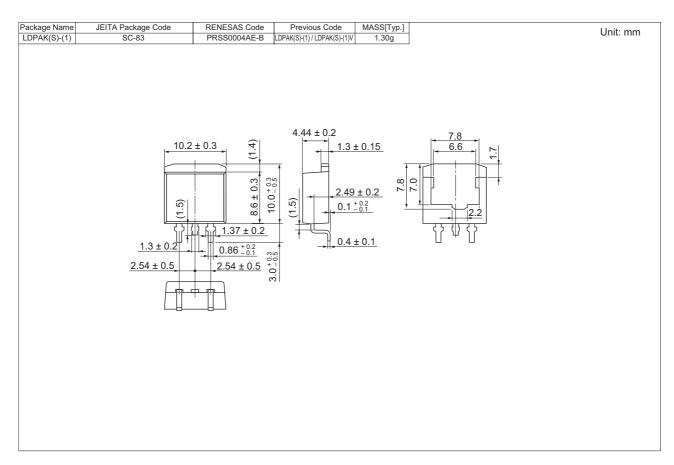


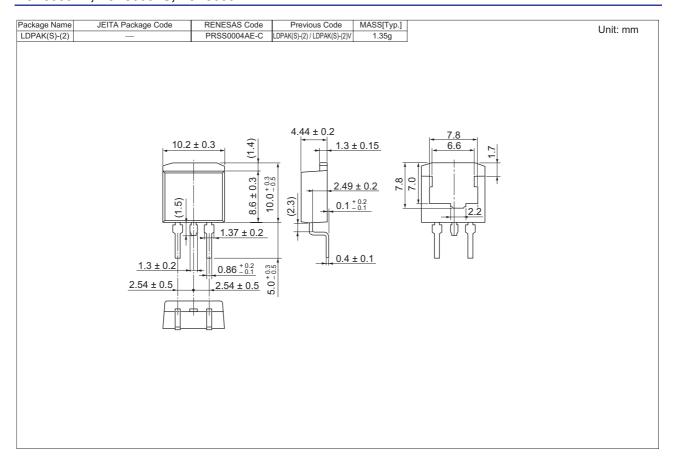




Package Dimensions







Ordering Information

Part Name	Quantity	Shipping Container		
H5N5006LD-E	500 pcs	Box (Conductive Sack)		
H5N5006LSTL-E	1000 pcs	Taping		
H5N5006LMTL-E	1000 pcs	Taping		

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Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510